Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-314-1543

	ure Material:
Metal	
Overa	II Length:
Betwee	en 0.169 inches and 0.180 inches
Termir	nal Length:
Betwee	en 0.500 inches and 0.560 inches
Overal	Il Diameter:
0.360 i	nches
Functi	on For Which Designed:
Rectifie	er
Joint E	Electronic Device Engineering Council/jedec/case Outline Designation:
To-39	
Mount	ing Method:
Termin	al
Termir	nal Circle Diameter:
Betwee	en 0.190 inches and 0.210 inches
Featur	res Provided:
Herme	tically sealed case
Semic	onductor Material:
Silicon	
Voltag	e Rating In Volts Per Characteristic:
45.0 re	epetitive peak reverse voltage and 45.0 working peak reverse voltage, peak total value and 54.0 nonrepetitive peak reverse voltage
Currer	nt Rating Per Characteristic:
2.00 ar	mperes operating voltage dc and 4.00 amperes forward current, average and 80.00 amperes forward current, average preset
Maxim	um Operating Tempurature Per Measurement Point:
175.0 0	degrees celsius junction
Termir	nal Type And Quantity:
3 unins	sulated wire lead
Shelf I	Life:
N/a	
Unit O	f Measure:
Demili	tarization:
No	
Fiig:	
	0